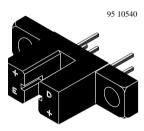
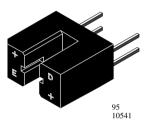
# **TCSS1100/TCSS2100**

# **Transmissive Optical Sensor**

#### **Description**

This device has a compact construction where the emitting light sources and the detectors are located face to face on the same optical axes. The operating wavelength is 950 nm. The detector consists of a photologic-IC with Schmitt-trigger and open collector output.





### **Applications**

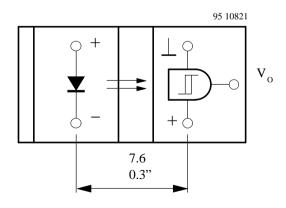
- Detection of opaque material, documents etc.
- Paper position sensor in copy machines.

Position sensor for shaft encoder.

#### **Features**

- Output: "LOW" when infrared beam is not interrupted
- Inverter-open collector
- TTL compatible
- Built in voltage regulator
- Case plastic polycarbonate-protected against ambient light
- No adjustment necessary
- Applicable connector AMP 171 825-3
- Aperture size 1 mm
- Two package variations

#### **Pin Connection**



Rev. A1: 22.09.1995

# **TCSS1100/TCSS2100**

**TELEFUNKEN Semiconductors** 

## **Absolute Maximum Ratings**

#### **Input (Emitter)**

Parameters	Test Conditions	Symbol	Value	Unit
Reserve voltage		$V_{R}$	6	V
Forward current		$I_{\mathrm{F}}$	60	mA
Forward surge current	$t_p \le 10 \ \mu s$	I <sub>FSM</sub>	3	A
Power dissipation	$T_{amb} \le 25^{\circ}C$	$P_{V}$	100	mW
Junction temperature		T <sub>i</sub>	100	°C

#### **Output (Detector)**

Parameters	Test Conditions	Symbol	Value	Unit
Supply voltages		$V_{S1}$	16	V
		$V_{S2}$	20	V
Output current		I <sub>o</sub>	20	mA
Power dissipation	$T_{amb} \le 25^{\circ}C$	$P_{v}$	50	mW
Junction temperature		Ti	100	°C

## Coupler

Parameters	Test Conditions	Symbol	Value	Unit
Total power dissipation	$T_{amb} \le 25^{\circ}C$	P <sub>tot</sub>	150	mW
Ambient temperature range		T <sub>amb</sub>	-25 to +85	°C
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C
Soldering temperature	2 mm from case, $t \le 5$ s	T <sub>sd</sub>	260	°C

## **Electrical Characteristics** $T_{amb} = 25^{\circ}C$

## **Input (Emitter)**

Parameters	Test Conditions	Type	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	$I_F = 50 \text{ mA}$		$V_{\mathrm{F}}$		1.25	1.6	V
Breakdown voltage	$I_R = 100 \mu A$		B <sub>(BR)</sub>	6			V
Junction capacitance	$V_R = 0$ , $f = 1$ MHz		C <sub>i</sub>		50		pF

#### **Output (Detector)**

Parameters	Test Conditions	Туре	Symbol	Min.	Тур.	Max.	Unit
Supply voltage range			$V_{S1}$	4.5		16	V

#### Coupler

Parameters	Test Conditions	Type	Symbol	Min.	Тур.	Max.	Unit
Supply current	$V_{S1} = 16 \text{ V}$		$I_{S1}$		3	5	mA
Output current	$V_{S1} = V_{S2} = 16$ V, $I_F = 0$		I <sub>OH</sub>			1	μΑ
Input threshold current	$V_{S1} = 5 V$		I <sub>FT</sub>		5	10	mA
Hysteresis	$V_{S1} = 5 V$		I <sub>Foff</sub> /I <sub>Fon</sub>		80		%
Output voltage	$I_{OL} = 16 \text{ mA},$ $I_{F} \ge I_{TF},$ $V_{S1} = 5 \text{ V}$		V <sub>OL</sub>		0.15	0.4	V
Switching frequency	$I_F 3x I_{FT},$ $V_{S1} = V_{S2} = 5 V,$ $R_L = 1 k\Omega$		$f_{sw}$		200		kHz

2 (4) Rev. A1: 22.09.1995

# **TCSS1100/TCSS2100**

#### **Switching Characteristics**

 $V_{S1} = V_{S2} = 5 \text{ V}, I_F = 3 \text{ x } I_{FT}, R_L = 1 \text{ k}\Omega, \text{ see test circuit}$ 

Parameters	Test Conditions	Symbol	Value	Unit
Rise time		t <sub>r</sub>	50	ns
Turn-on time		t <sub>on</sub>	1	μs
Fall time		t <sub>f</sub>	20	ns
Turn-off time		$t_{ m off}$	3	μs

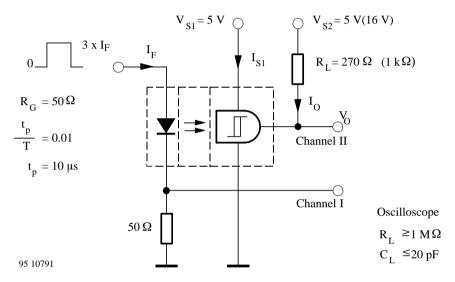


Figure 1. Test circuit for:  $t_r$ ,  $t_{on}$ ,  $t_f$ ,  $t_{off}$ 

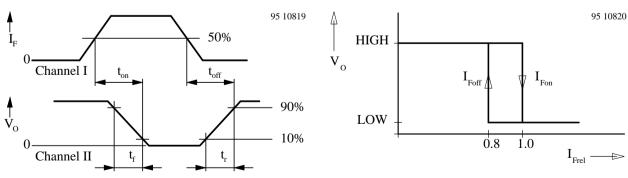


Figure 2. Pulse diagram

Figure 3. Hysteresis

Rev. A1: 22.09.1995

# **TEMIC**

# TCSS1100/TCSS2100

**TELEFUNKEN Semiconductors** 

#### **Ozone Depleting Substances Policy Statement**

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

4 (4) Rev. A1: 22.09.1995